

March 2015

FGB20N60SF 600 V, 20 A Field Stop IGBT

Features

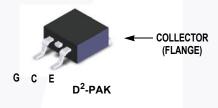
- · High Current Capability
- Low Saturation Voltage: V_{CE(sat)} =2.2 V @ I_C = 20 A
- High Input Impedance
- Fast Switching : E_{OFF} = 8 uJ/A
- · RoHS Compliant

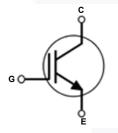
Applications

· Solar Inverter, UPS, Welder, PFC

General Description

Using novel field stop IGBT technology, Fairchild's field stop IGBTs offer the optimum performance for solar inverter, UPS, welder and PFC applications where low conduction and switching losses are essential.





Absolute Maximum Ratings

Symbol	Description		Ratings	Unit
V _{CES}	Collector to Emitter Voltage		600	V
V	Gate to Emitter Voltage		±20	
V_{GES}	Transient Gate-to-Emitter Voltage	±30	V	
I _C	Collector Current	@ T _C = 25°C	40	Α
ic	Collector Current	$@T_C = 100^{\circ}C$	20	Α
I _{CM (1)}	Pulsed Collector Current	@ T _C = 25°C	60	Α
P _D	Maximum Power Dissipation	$@T_C = 25^{\circ}C$	208	W
	Maximum Power Dissipation	$@T_C = 100^{\circ}C$	83	W
T _J	Operating Junction Temperature		-55 to +150	°C
T _{stg}	Storage Temperature Range		-55 to +150	°C
T _L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	°C	

Notes

Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	-	0.6	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (PCB Mount)(2)	-	40	°C/W	

Notes:

2: Mounted on 1" square PCB(FR4 or G-10 material)

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGB20N60SF	FGB20N60SF	D ² -PAK	Reel	13" Dia	N/A	800

Electrical Characteristics of the IGBT $T_C = 25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics					
BV _{CES}	Collector to Emitter Breakdown Voltage	V_{GE} = 0 V, I_{C} = 250 μ A	600	-	-	V
ΔBV _{CES} / ΔΤ _J	Temperature Coefficient of Breakdown Voltage	$V_{GE} = 0 \text{ V, } I_{C} = 250 \mu\text{A}$	-	0.6	-	V/°C
I _{CES}	Collector Cut-Off Current	V _{CE} = V _{CES} , V _{GE} = 0 V	-	-	250	μΑ
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0 V$		-	±400	nA
On Charac	teristics					
V _{GE(th)}	G-E Threshold Voltage	$I_C = 250 \mu A, V_{CE} = V_{GE}$	4.0	5.0	6.5	V
02()		I _C = 20 A, V _{GE} = 15 V	-	2.2	2.8	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	I _C = 20 A, V _{GE} = 15 V, T _C = 125°C	-	2.4	-	V
Dynamic C	haracteristics					
C _{ies}	Input Capacitance		-	940	-	pF
C _{oes}	Output Capacitance	$V_{CE} = 30 \text{ V}, V_{GE} = 0 \text{ V},$ f = 1 MHz	-	110	-	pF
C _{res}	Reverse Transfer Capacitance	- 1 - 1 101112	-	40	-	pF
Switching	Characteristics					
t _{d(on)}	Turn-On Delay Time		-	13	-	ns
t _r	Rise Time		-	16	-	ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 400 \text{ V}, I_{C} = 20 \text{ A},$	-	90	- ,	ns
t _f	Fall Time	$R_G = 10 \Omega, V_{GE} = 15 V,$	-	24	48	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 25°C	-	0.37	-	mJ
E _{off}	Turn-Off Switching Loss		-	0.16	/	mJ
E _{ts}	Total Switching Loss		-	0.53	- /	mJ
t _{d(on)}	Turn-On Delay Time		-	12	-	ns
t _r	Rise Time		-	16	-	ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 400 \text{ V}, I_{C} = 20 \text{ A},$	-	95	-	ns
t _f	Fall Time	$R_G = 10 \Omega$, $V_{GE} = 15 V$, Inductive Load, $T_C = 125^{\circ}C$	-	28	-	ns
E _{on}	Turn-On Switching Loss		-	0.4	-	mJ
E _{off}	Turn-Off Switching Loss		-	0.28	-	mJ
E _{ts}	Total Switching Loss		-	0.69	-	mJ
Qg	Total Gate Charge		-	65	-	nC
Q _{ge}	Gate to Emitter Charge	$V_{CE} = 400 \text{ V}, I_{C} = 20 \text{ A},$ $V_{GF} = 15 \text{ V}$	-	7	-	nC
Q _{gc}	Gate to Collector Charge	GE 'G'	-	33	-	nC

Figure 1. Typical Output Characteristics

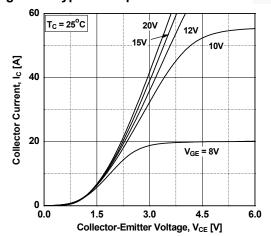


Figure 2. Typical Output Characteristics

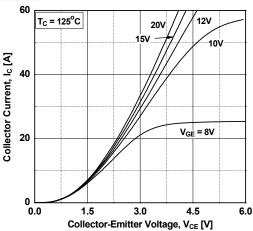


Figure 3. Typical Saturation Voltage Characteristics

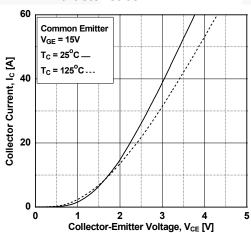


Figure 4. Transfer Characteristics

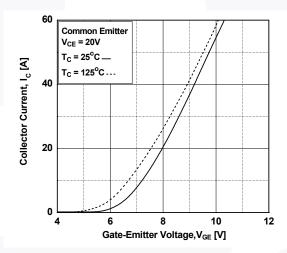


Figure 5. Saturation Voltage vs. Case
Temperature at Variant Current Level

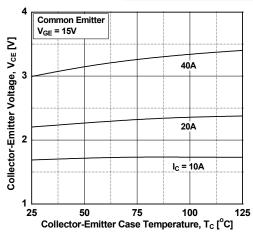


Figure 6. Saturation Voltage vs. V_{GE}

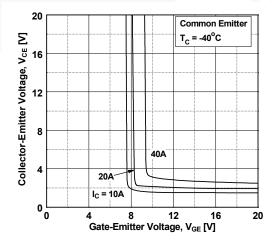
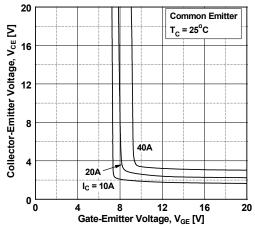


Figure 7. Saturation Voltage vs. V_{GE}



Outo Emittor Voltago, VGE [V]

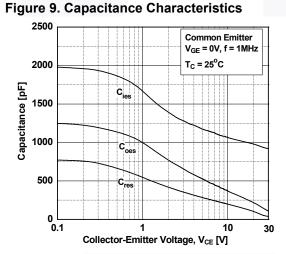


Figure 11. SOA Characteristics

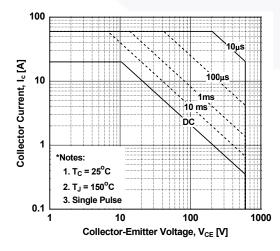


Figure 8. Saturation Voltage vs. V_{GE}

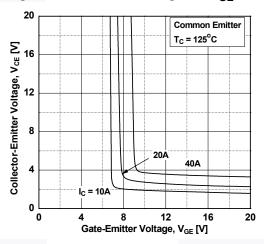


Figure 10. Gate charge Characteristics

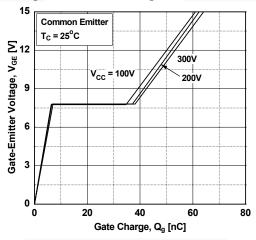


Figure 12. Turn-on Characteristics vs. Gate Resistance

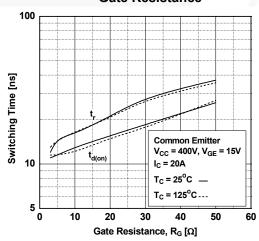


Figure 13. Turn-off Characteristics vs.
Gate Resistance

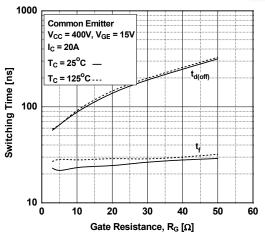


Figure 15. Turn-off Characteristics vs.

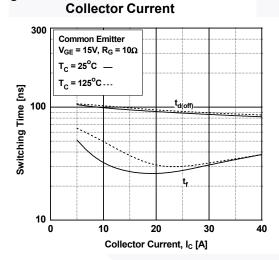


Figure 17. Switching Loss vs. Collector Current

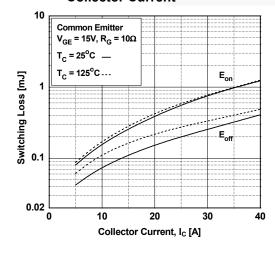


Figure 14. Turn-on Characteristics vs.
Collector Current

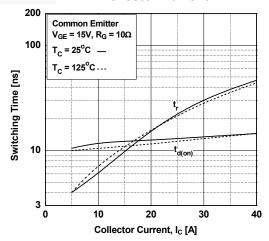


Figure 16. Switching Loss vs.

Gate Resistance

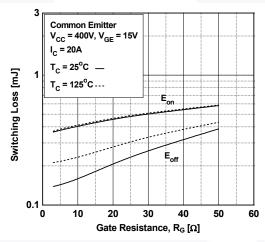
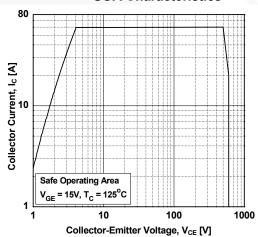
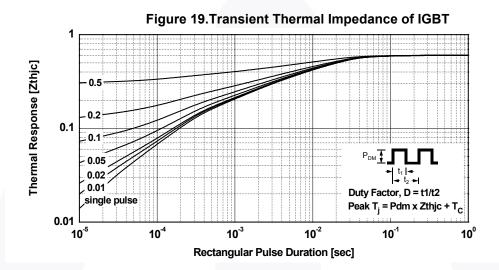
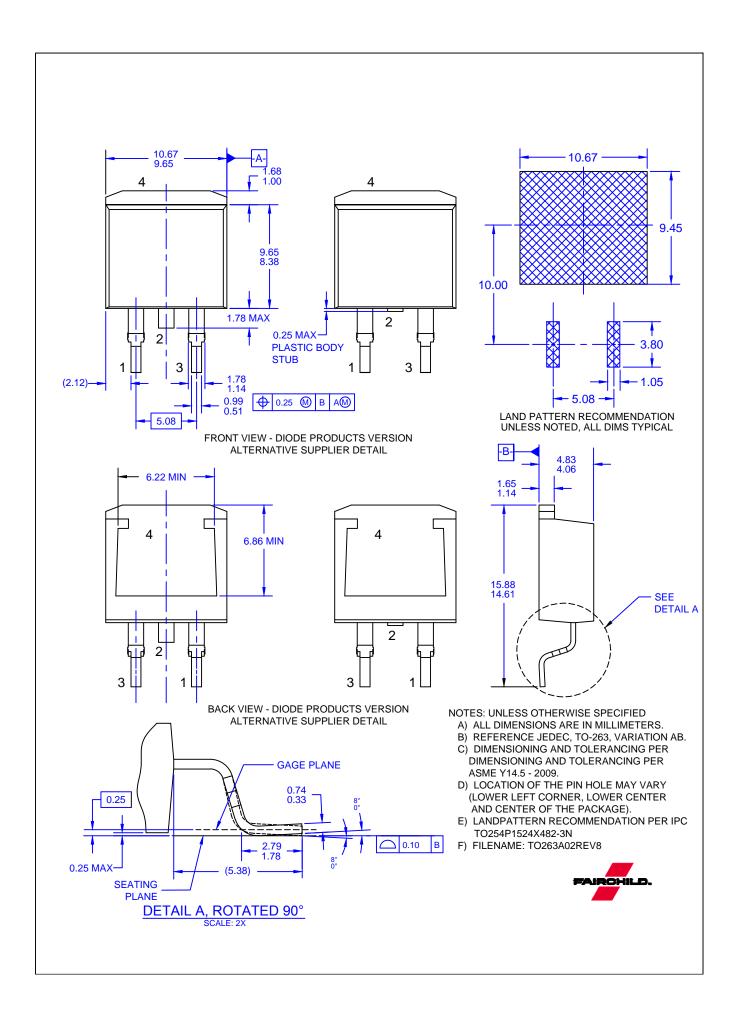


Figure 18. Turn off Switching SOA Characteristics











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Definition of Terms					
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